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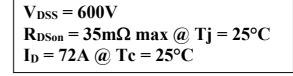


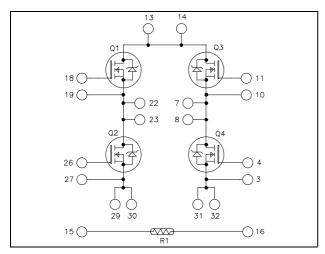






### Full - Bridge Super Junction MOSFET Power Module





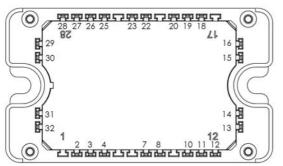
### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

#### **Features**

#### • Super junction MOSFET

- Ultra low R<sub>DSon</sub>
- Low Miller capacitance
- Ultra low gate charge
- Avalanche energy rated
- Very rugged
- Kelvin source for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring



All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS Compliant

#### All ratings (a) $T_i = 25^{\circ}C$ unless otherwise specified

### Absolute maximum ratings (per super junction MOSFET)

Symbol	Parameter		Max ratings	Unit	
$V_{\mathrm{DSS}}$	Drain - Source Voltage		600	V	
Ţ		$T_c = 25$ °C	72		
$I_D$	Continuous Drain Current	$T_c = 80$ °C	54	A	
$I_{DM}$	Pulsed Drain current		200		
$V_{GS}$	Gate - Source Voltage		±20	V	
R <sub>DSon</sub>	Drain - Source ON Resistance		35	$m\Omega$	
$P_D$	Power Dissipation $T_c = 25^{\circ}C$		416	W	
$I_{AR}$	Avalanche current (repetitive and non repetitive)		20	A	
$E_{AR}$	Repetitive Avalanche Energy		1	m I	
Eas	Single Pulse Avalanche Energy		1800	mJ	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

### **Electrical Characteristics** (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 600V$			40	μA
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 72A$			35	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 5.4 \text{mA}$	2.1	3	3.9	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

### **Dynamic Characteristics** (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		14		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		5.13		nF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		0.42		
$Q_{\mathrm{g}}$	Total gate Charge	$V_{GS} = 10V$		518		
$Q_{\mathrm{gs}}$	Gate – Source Charge	$V_{Bus} = 300V$		58		nC
$Q_{\mathrm{gd}}$	Gate – Drain Charge	$I_D = 72A$		222		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching @ 125°C		21		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		30		ns
$T_{d(off)} \\$	Turn-off Delay Time	$V_{\text{Bus}} = 400V$ $I_{\text{D}} = 72A$		283		
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.5\Omega$		84		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		1340		Ţ
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 400V$ $I_D = 72A, R_G = 2.5\Omega$		1960		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V$ , $V_{Bus} = 400V$ $I_D = 72A$ , $R_G = 2.5\Omega$		2192		Т
$E_{\text{off}}$	Turn-off Switching Energy			2412		μJ
$R_{thJC}$	Junction to Case Thermal Resistance	;			0.30	°C/W

### **Source - Drain diode ratings and characteristics** (per super junction MOSFET)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_S$	Continuous Source current		$Tc = 25^{\circ}C$		72		Α
	(Body diode)		$Tc = 80^{\circ}C$		54		A
$V_{\mathrm{SD}}$	Diode Forward Voltage	$V_{GS} = 0V$ , $I_S = -72A$	L			1.2	V
dv/dt	Peak Diode Recovery					6	V/ns
$t_{rr}$	Reverse Recovery Time	$I_{S} = -72A$	$T_j = 25^{\circ}C$		580		ns
Qrr	Reverse Recovery Charge	$V_R = 350V$ $di_S/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		46		μС

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

 $I_S \le -72A$   $di/dt \le 200A/\mu s$   $V_R \le V_{DSS}$   $T_i \le 150$ °C



### Thermal and package characteristics

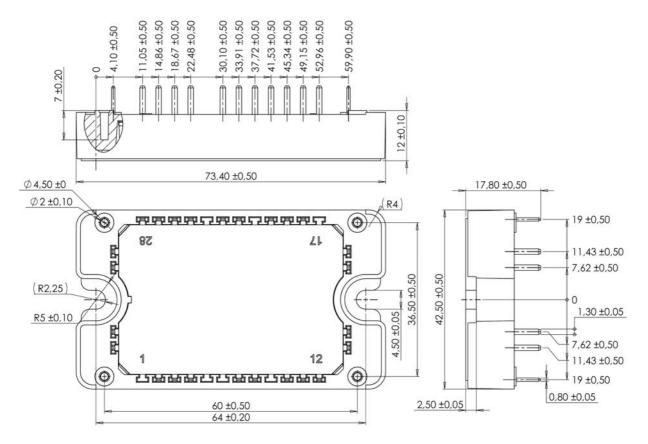
Symbol	Characteristic			Min	Max	Unit
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000		V
$T_{\rm J}$	Operating junction temperature range			-40	150	
$T_{JOP}$	Recommended junction temperature under switching conditions			-40	T <sub>J</sub> max -25	°C
$T_{STG}$	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	100	
Torque	Mounting torque	To heatsink	M4	2.5	4.7	N.m
Wt	Package Weight				110	g

### Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Typ	Max	Unit
R <sub>25</sub>	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T <sub>C</sub> =100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$
 R<sub>T</sub>: Thermistor value at T

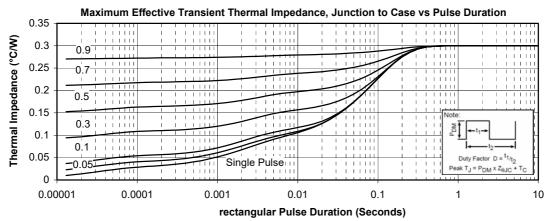
### Package outline (dimensions in mm)

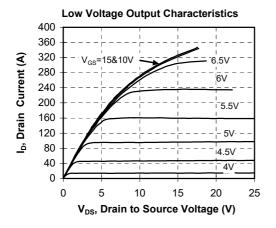


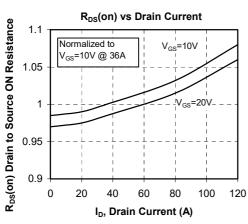
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

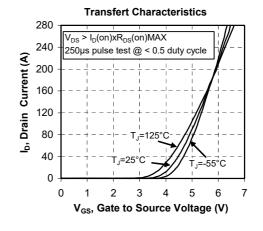


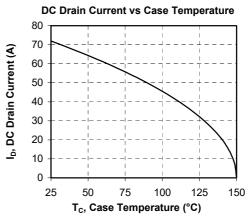
### **Typical Performance Curve**



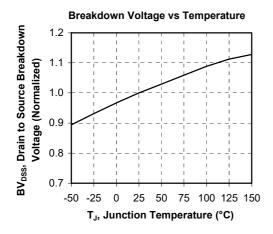


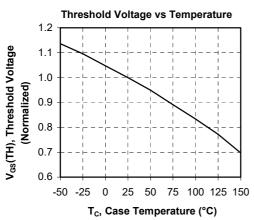


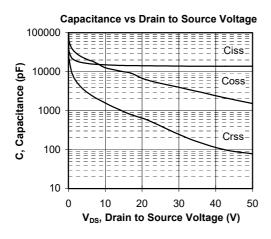


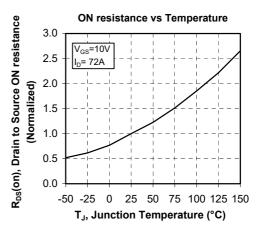


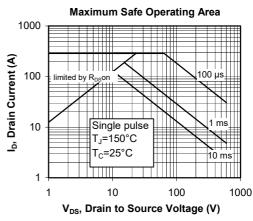


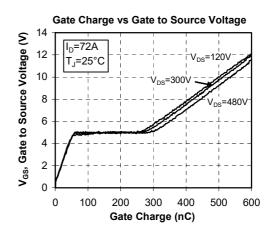




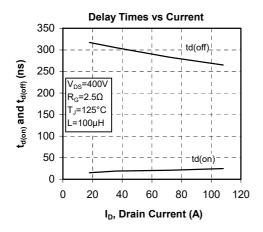


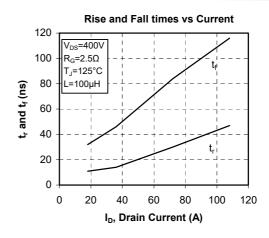


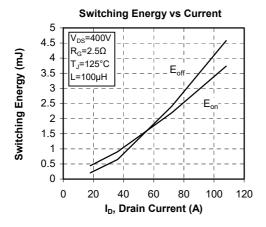


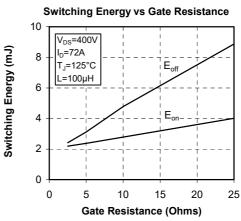


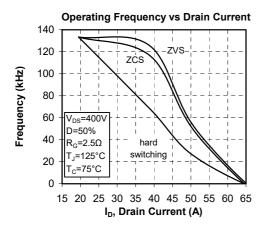


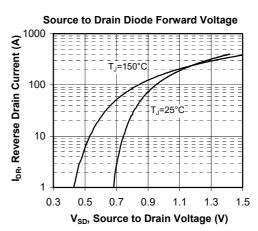












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